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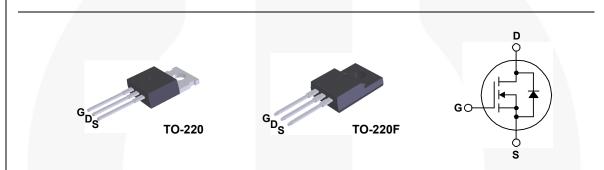
FQP6N90C / FQPF6N90C **N-Channel QFET® MOSFET** 900 V, 6.0 A, 2.3 Ω

Description

This N-Channel enhancement mode power MOSFET is • 6.0 A, 900 V, R_{DS(on)} = 2.3 Ω (Max.) @ V_{GS} = 10 V, produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state . Low Gate Charge (Typ. 30 nC) resistance, and to provide superior switching performance • Low Crss (Typ. 11 pF) and high avalanche energy strength. These devices are suitable for switched mode power supplies, active power • 100% Avalanche Tested factor correction (PFC), and electronic lamp ballasts.

Features

- $I_{D} = 3.0 \text{ A}$



Absolute Maximum Ratings T_c = 25°C unless otherwise noted.

Symbol	Parameter	FQP6N90C FQPF6N90C		Unit	
V _{DSS}	Drain-Source Voltage	9	V		
I _D	Drain Current - Continuous ($T_C = 25^{\circ}C$)		6	6 *	А
	- Continuous (T _C = 100°C)		3.8	3.8 *	А
DM	Drain Current - Pulsed	(Note 1)	24	24 *	А
V _{GSS}	Gate-Source Voltage	±	V		
E _{AS}	Single Pulsed Avalanche Energy	6	mJ		
AR	Avalanche Current	(Note 1)	6		А
E _{AR}	Repetitive Avalanche Energy (Note 1)		10	mJ	
dv/dt	Peak Diode Recovery dv/dt (Note 3)		4.5		V/ns
PD	Power Dissipation ($T_C = 25^{\circ}C$)	167	56	W	
	- Derate above 25°C	1.43	0.48	W/°C	
T _J , T _{STG}	Operating and Storage Temperature Range	-55 to	°C		
TL	Maximum lead temperature for soldering, 1/8" from case for 5 seconds	3	°C		

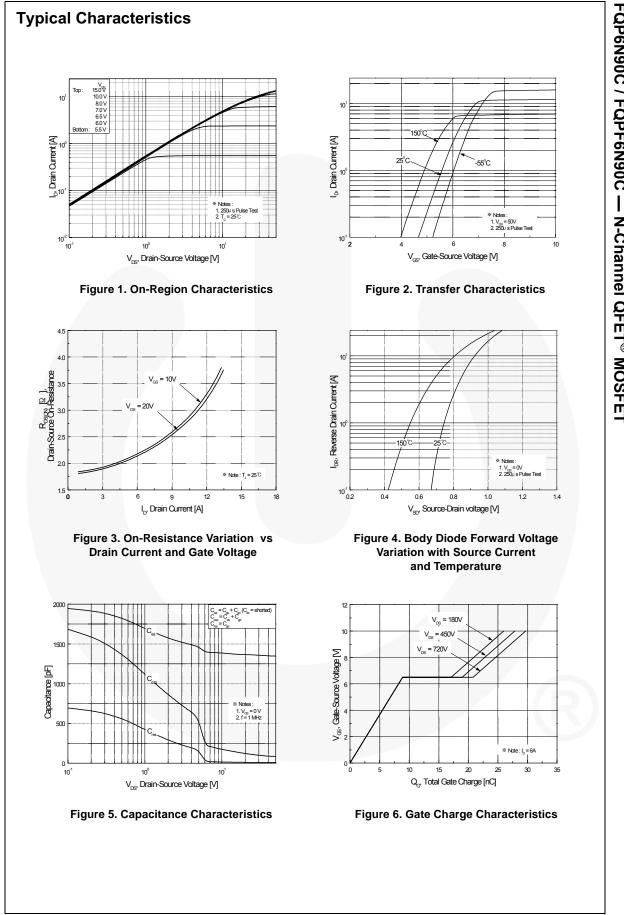
* Drain current limited by maximum junction temperature.

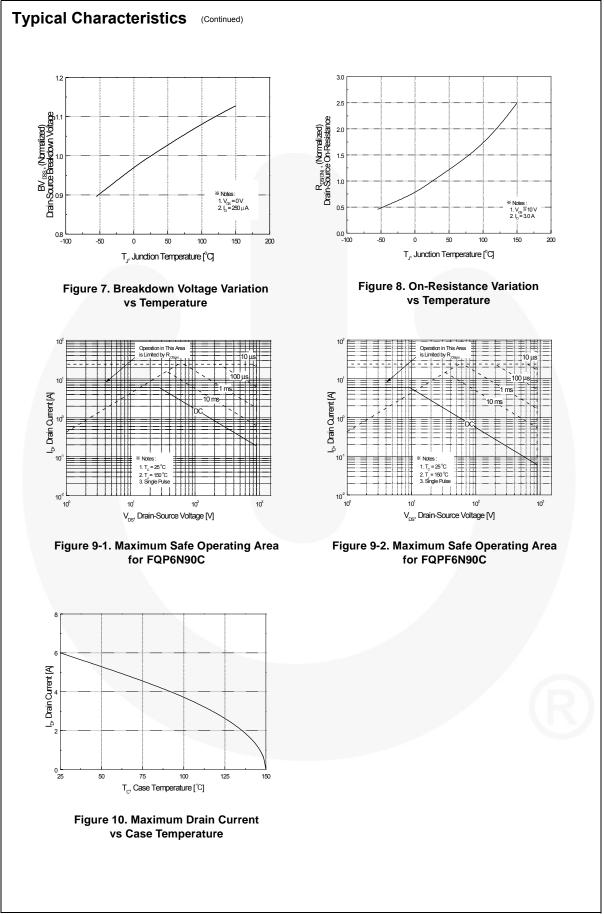
Thermal Characteristics

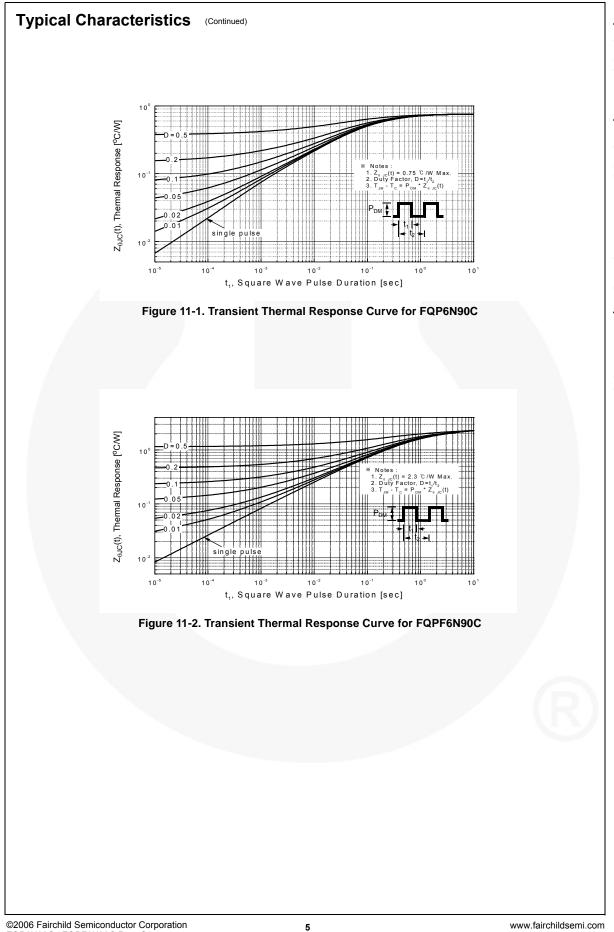
Symbol	Parameter	FQP6N90C	FQPF6N90C	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	0.75	2.25	°C/W	
$R_{\theta CS}$	Thermal Resistance, Case-to-Sink Typ, Max.	0.5		°C/W	
R_{\thetaJA}	Thermal Resistance, Junction-to-Ambient, Max.	62.5	62.5	°C/W	

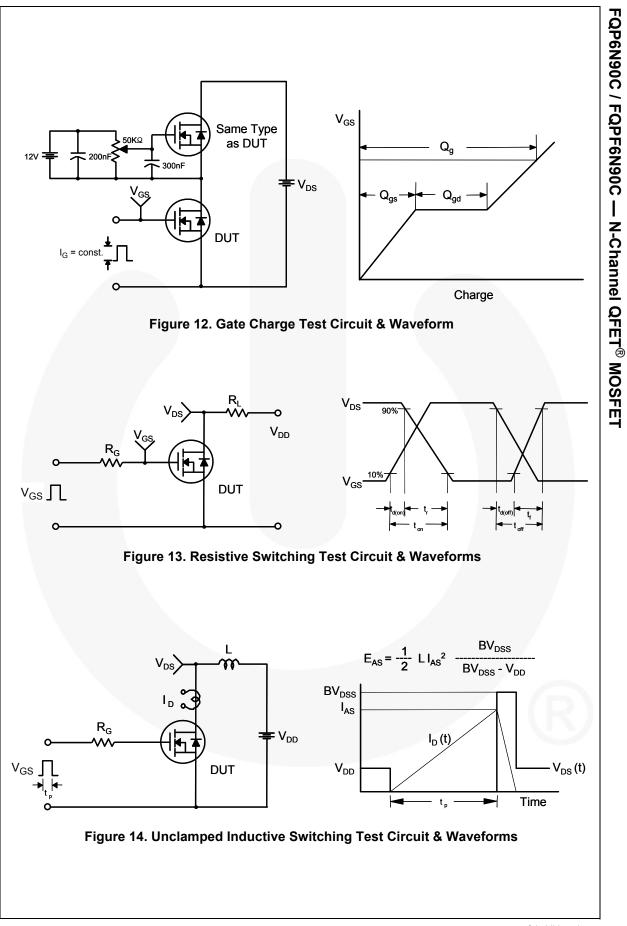
December 2013

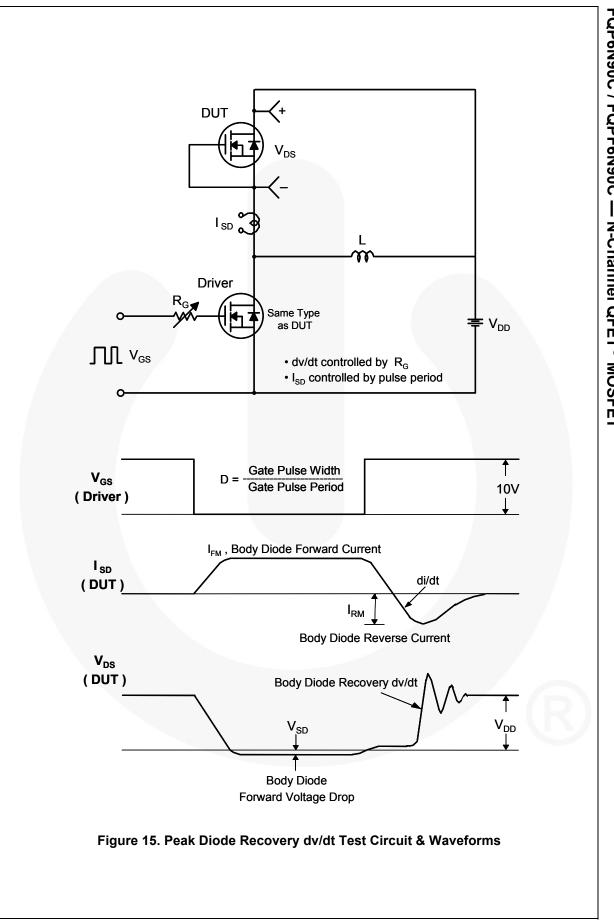
Part NumberTop MarkPackFQP6N90CFQP6N90CTO-2FQPF6N90CFQPF6N90CTO-2		Top Mark	Pack	age	age Packing Method Reel S		Size	Tape Width		Quantity	
		FQP6N90C TO-		220			4	N/A		50 units	
		20F Tube N/			4	N/A		50 units			
lectric	cal Cha	racteristics	T _C = 25°C	c unless of	herwise noted						-i
Symbol		Parameter			Test Cor	nditions		Min.	Тур.	Max.	Unit
	racterist	ics									
SV _{DSS}	Drain-Source Breakdown Voltage		V_{GS} = 0 V, I _D = 250 µA			900			V		
BV _{DSS} MTJ	Breakdown Voltage Temperature Coefficient Zero Gate Voltage Drain Current		$I_D = 250 \ \mu$ A, Referenced to 25° C					1.07		V/°C	
DSS			V_{DS} = 900 V, V_{GS} = 0 V V_{DS} = 720 V, T_{C} = 125°C						10 100	μA μA	
GSSF	Gate-Bod	y Leakage Current,	Forward	$V_{GS} = 30 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$						100	nA
GSSR		y Leakage Current,		$V_{GS} = -30 \text{ V}, V_{DS} = 0 \text{ V}$					-100	nA	
	racterist			00	, 00	-					
GS(th)	-	eshold Voltage	-	V _{DS} =	V_{GS} , $I_D = 2$	250 μA		3.0		5.0	V
RDS(on)	Static Dra On-Resist			V _{GS} =	10 V, I _D =	3 A			1.93	2.3	Ω
FS	Forward 1	ransconductance		V _{DS} = 50 V, I _D = 3 A				5.5		S	
)ynam i _{Ziss}	c Characteristics Input Capacitance		V _{DS} = 25 V, V _{GS} = 0 V,				1360	1770	pF		
oss	Output Ca	utput Capacitance everse Transfer Capacitance		f = 1.0 MHz				110	145	pF	
rss	Reverse 7							11	15	pF	
Switchi	ng Char	acteristics									
d(on)	Turn-On Delay Time		14 450141 0.4				35	80	ns		
	Turn-On F	Rise Time	-		V_{DD} = 450 V, I_D = 6 A, R _G = 25 Ω			90	190	ns	
l(off)	Turn-Off [Delay Time		n _G -	2.5 12				55	120	ns
(-)	Turn-Off F	all Time					(Note 4)		60	130	ns
2 _g	Total Gate	e Charge		V _{De} =	720 V, I _D =	• 6 A,			30	40	nC
) _{gs}	Gate-Sou	rce Charge			$V_{GS} = 10 V$			-	9.0		nC
) _{gd}	Gate-Drai	n Charge					(Note 4)	-	12		nC
	ource Di	ode Characteri	istics ar	nd Ma	ximum R	atings			1 1		
3		Continuous Drain-S				•				6.0	Α
SM		aximum Pulsed Drain-Source Diode F								24	A
SD					$V_{GS} = 0 V, I_S = 6 A$)	1.4	V
r	Reverse F	rse Recovery Time		$V_{GS} = 0 V, I_S = 6 A,$				630		ns	
) ^{ut}	Reverse Recovery Charge			dI _F / dt = 100 A/μs				6.9		μC	
L = 34 mH, I	$I_{AS} = 6 \text{ A}, V_{DD}$ li/dt \leq 200 A/µs	th limited by maximum jur = 50 V, R _G = 25 Ω, starting s , V _{DD} \leq BV _{DSS} , starting	$T_1 = 25^{\circ}C.$	ature.							

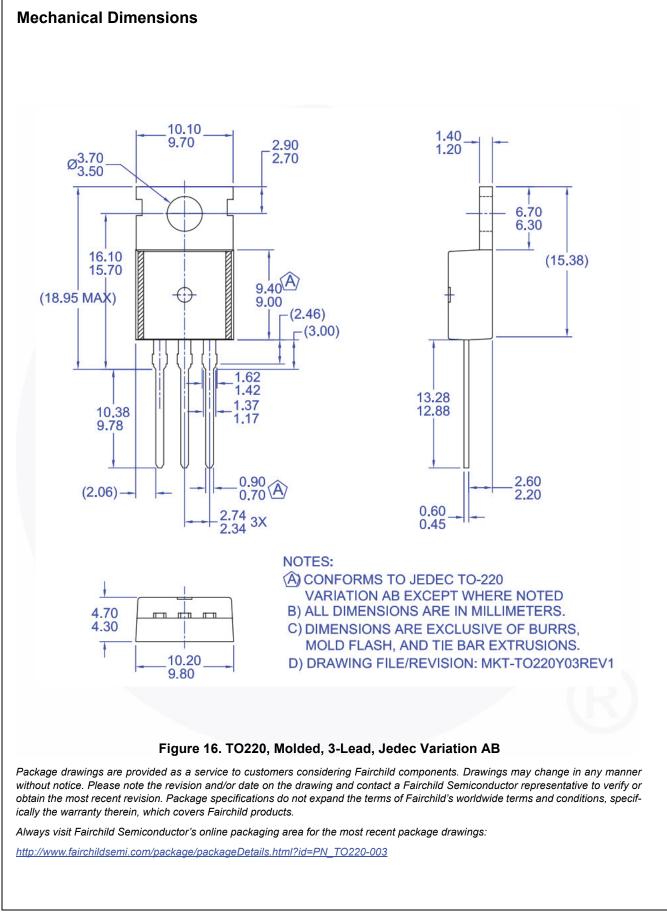








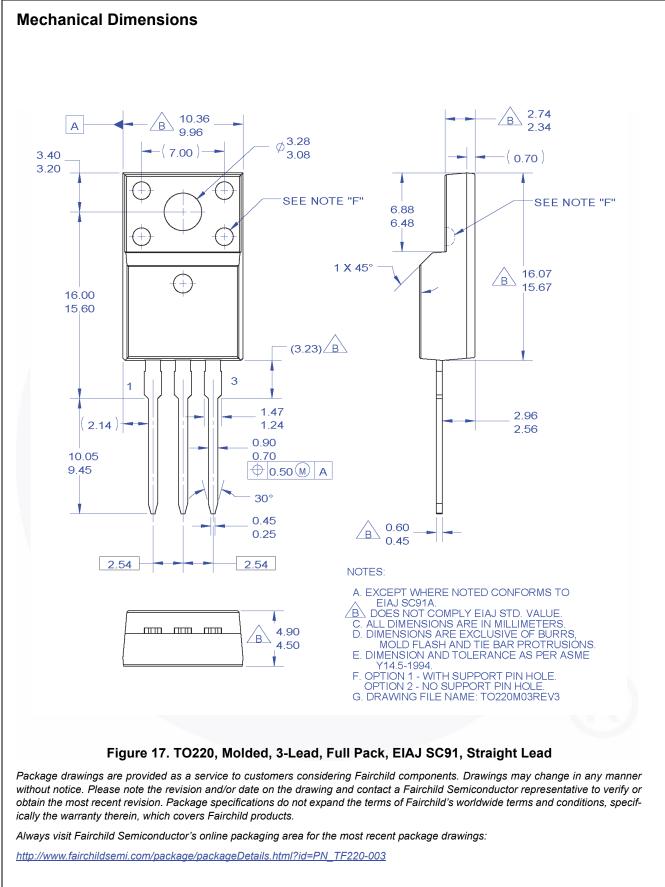




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N-Channel QFET[®] MOSFET



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Preliminary

No Identification Needed

Obsolete

First Production

Full Production

Not In Production

notice to improve design.

Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.

Datasheet contains specifications on a product that is discontinued by Fairchild

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